

MURD860 Green Products

MURD860 ULTRAFAST PLASTIC RECTIFIER

#### **Applications:**

**Technical Data** 

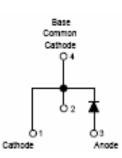
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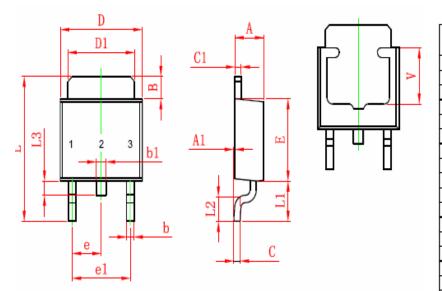
- Switching Power Supply
- Power Switching Circuits
- General Purpose

### Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Mechanical Dimensions (In mm):**

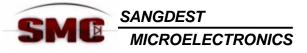




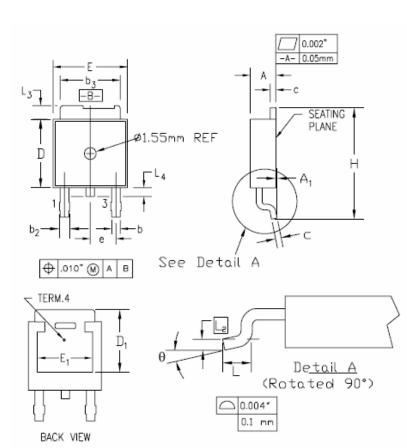
fumbal	Dimensions In Millimeters		
Symbol	Min.	Max.	
А	2.200	2.400	
A1	0.000	0.127	
В	1.350	1.650	
b	0.500	0.700	
b1	0.700	0.900	
С	0.430	0.580	
c1	0.430	0.580	
D	6.350	6.650	
D1	5.200	5.400	
E	5.400	5.700	
е	2.300 TYP.		
e1	4.500	4.700	
L	9.500	9.900	
L1	2.550	2.900	
L2	1.400	1.780	
L3	0.600	0.900	
V	3.800 REF.		

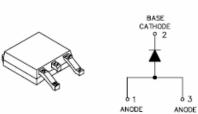
## **OPTION 1**

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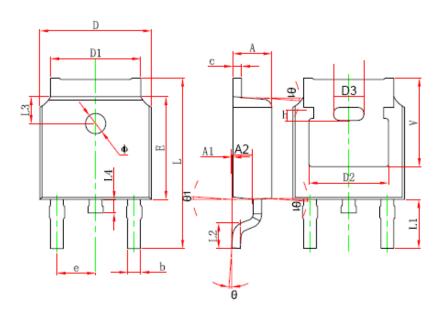


SYNDOL	INCHES		MILLIMETERS	
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	0.086	0.094	2.19	2.38
A1	-	0.005	-	0.13
b	0.025	0.035	0.64	0.89
b2	0.033	0.045	0.84	1.14
b3	0.205	0.215	5.21	5.46
С	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
D1	0.205	-	5.21	-
E	0.250	0.265	6.35	6.73
E1	0.190	-	4.83	-
е	0.090 BSC		2.29 BSC	
Н	0.380	0.410	9.65	10.41
L	0.055	0.070	1.40	1.78
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	0.025	0.040	0.64	1.01
θ	0°	8°	0°	8°

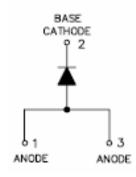
**OPTION 2** 



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Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.380	0.087	0.094	
A1	0.000	0.100	0.000	0.004	
b	0.710	0.810	0.028	0.032	
с	0.460	0.560	0.018	0.022	
D	6.500	6.700	0.256	0.264	
D1	5.130	5.460	0.202	0.215	
D2	4.830	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	REF.	0.114 REF.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 REF.		0.063 REF.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
A2	0.910	1.110	0.036	0.044	
V	5.350 REF.		0.211 REF.		
D3	1.778REF.		0.070	REF.	
h	0.762REF.		0.030REF.		
<del>0</del> 1	7°		7°		



## **OPTION 3**

DPAK



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### **Green Products**

### Marking Diagram:



Where XXXXX is YYWWL

MUR	= Device Type
D	= Package type
8	= Forward Current (8A)
60	= Reverse Voltage (600V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping
MURD860	DPAK (Pb-Free)	2500 pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



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### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MURD860	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	600	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	420	V
Average Rectified Output Current @T <sub>A</sub> =100°C	lo	8.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	110	A
Forward Voltage (per element) $@I_F = 8.0A, T_J=25^{\circ}C$	V <sub>FM1</sub>	2.2	V
@I <sub>F</sub> = 8.0A,T <sub>J</sub> =100°C	V <sub>FM2</sub>	2.0	V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	I <sub>RM</sub>	5.0 50	μA
Maximum Reverse Recovery Time (Note 1)	Trr	50	ns
Max. Voltage Rate of Change	dv/dt	10,000	V/µs
Typical Thermal Resistance Junction to Ambient (Note 2)	$R_{ extsf{ heta}JA}$	25	K/W
Storage Temperature Range	$T_{STG}$ , $T_{J}$	-55 to +150	°C
Approximate Weight	wt	0.39	g
Case Style		DPAK	

Note: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

2. Mount on Cu-Pad Size 16mm×16mm on P.C.B.



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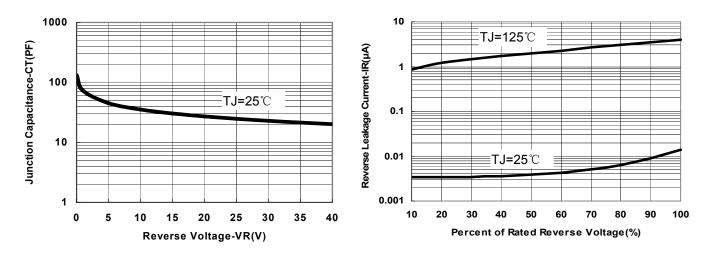




Fig.2-Typical Reverse Characteristics

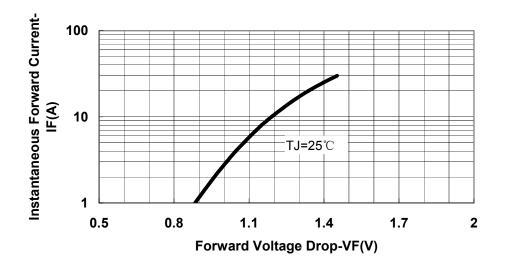


Fig.3-Typical Forward Voltage Drop Characteristics



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### Green Products

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